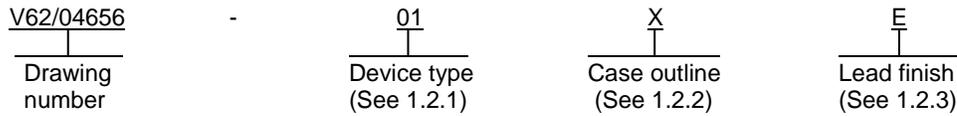


1. SCOPE

1.1 Scope. This drawing documents the general requirements of a high performance quadruple bus buffer gate with 3-state outputs microcircuit, with an operating temperature range of -40°C to +85°C for device 01 and an operating temperature range of -55°C to +125°C for device 02.

1.2 Vendor Item Drawing Administrative Control Number. The manufacturer's PIN is the item of identification. The vendor item drawing establishes an administrative control number for identifying the item on the engineering documentation:



1.2.1 Device type(s).

<u>Device type</u>	<u>Generic</u>	<u>Circuit function</u>
01	SN74LVC125A-EP	Quadruple bus buffer gate with 3-state outputs
02	SN74LVC125A-EP	Quadruple bus buffer gate with 3-state outputs

1.2.2 Case outlines. The case outlines are as specified herein.

<u>Outline letter</u>	<u>Number of pins</u>	<u>JEDEC PUB 95</u>	<u>Package style</u>
X	14	MO-153	Plastic small-outline
Y	14	MS-012	Plastic small-outline

1.2.3 Lead finishes. The lead finishes are as specified below or other lead finishes as provided by the device manufacturer:

<u>Finish designator</u>	<u>Material</u>
A	Hot solder dip
B	Tin-lead plate
C	Gold plate
D	Palladium
E	Gold flash palladium
Z	Other

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1.3 Absolute maximum ratings. 1/

Supply voltage range (V_{CC})	-0.5 V to 6.5 V
Input voltage range (V_I)	-0.5 V to 6.5 V 2/
Output voltage range (V_O)	-0.5 V to $V_{CC} + 0.5$ V 2/ 3/
Input clamp current (I_{IK}) ($V_I < 0$)	-50 mA
Output clamp current (I_{OK}) ($V_O < 0$)	-50 mA
Continuous output current (I_O)	± 50 mA
Continuous current through V_{CC} or GND	± 100 mA
Package thermal impedance (θ_{JA}): 4/	
Case outline X	113°C/W
Case outline Y	86.2°C/W
Storage temperature range (T_{STG})	-65°C to 150°C

1.4 Recommended operating conditions. 5/

Supply voltage range (V_{CC}):	
Operating	1.65 V to 3.6 V
Data retention only	1.5 V minimum
Minimum high level input voltage (V_{IH}):	
($V_{CC} = 1.65$ V to 1.95 V)	$0.65 \times V_{CC}$
($V_{CC} = 2.3$ V to 2.7 V)	1.7 V
($V_{CC} = 2.7$ V to 3.6 V)	2.0 V
Maximum low level input voltage (V_{IL}):	
($V_{CC} = 1.65$ V to 1.95 V)	$0.35 \times V_{CC}$
($V_{CC} = 2.3$ V to 2.7 V)	0.7 V
($V_{CC} = 2.7$ V to 3.6 V)	0.8 V
Input voltage range (V_I)	0.0 V to 5.5 V
Output voltage range (V_O)	0.0 V to V_{CC}
Maximum high level output current (I_{OH}):	
$V_{CC} = 1.65$ V	-4 mA
$V_{CC} = 2.3$ V	-8 mA
$V_{CC} = 2.7$ V	-12 mA
$V_{CC} = 3.0$ V	-24 mA
Maximum low level output current (I_{OL}):	
$V_{CC} = 1.65$ V	4 mA
$V_{CC} = 2.3$ V	8 mA
$V_{CC} = 2.7$ V	12 mA
$V_{CC} = 3.0$ V	24 mA
Maximum input transition rise or fall rate ($\Delta t/\Delta v$)	8 ns/V
Operating free-air temperature range (T_A):	
Case outline X	-40°C to +85°C
Case outline Y	-55°C to +125°C

1/ Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2/ The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

3/ The value of V_{CC} is provided in the recommended operating conditions table.

4/ The package thermal impedance is calculated in accordance with JESD 51-7.

5/ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation.

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2. APPLICABLE DOCUMENTS

JEDEC – SOLID STATE TECHNOLOGY ASSOCIATION (JEDEC)

- JEP95 – Registered and Standard Outlines for Semiconductor Devices
- JESD51-7 – High Effective Thermal Conductivity Test Board for Leaded Surface Mount Packages

(Copies of these documents are available online at <http://www.jedec.org> or from JEDEC – Solid State Technology Association, 3103 North 10th Street, Suite 240–S, Arlington, VA 22201.)

3. REQUIREMENTS

3.1 Marking. Parts shall be permanently and legibly marked with the manufacturer's part number as shown in 6.3 herein and as follows:

- A. Manufacturer's name, CAGE code, or logo
- B. Pin 1 identifier
- C. ESDS identification (optional)

3.2 Unit container. The unit container shall be marked with the manufacturer's part number and with items A and C (if applicable) above.

3.3 Electrical characteristics. The maximum and recommended operating conditions and electrical performance characteristics are as specified in 1.3, 1.4, and table I herein.

3.4 Design, construction, and physical dimension. The design, construction, and physical dimensions are as specified herein.

3.5 Diagrams.

3.5.1 Case outlines. The case outlines shall be as shown in 1.2.2 and figure 1.

3.5.2 Truth table. The truth table shall be as shown in figure 2.

3.5.3 Logic diagram. The logic diagram shall be as shown in figure 3.

3.5.4 Terminal connections. The terminal connections shall be as shown in figure 4.

3.5.5 Test circuit and timing waveforms. The test circuit and timing waveforms shall be as shown in figure 5.

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TABLE I. Electrical performance characteristics. 1/

Test	Symbol	Conditions	V _{CC}	Temperature, T _A	Device type	Limits		Unit
						Min	Max	
High level output voltage	V _{OH}	I _{OH} = -100 μA	1.65 V to 3.6 V	Device 01: 25°C, -40°C to 85°C, Device 02: 25°C, -55°C to 125°C	01, 02	V _{CC} - 0.2		V
		I _{OH} = -4 mA	1.65 V			1.2		
		I _{OH} = -8 mA	2.3 V			1.7		
		I _{OH} = -12 mA	2.7 V			2.2		
			3.0 V			2.4		
		I _{OH} = -24 mA	3.0 V			2.2		
Low level output voltage	V _{OL}	I _{OL} = 100 μA	1.65 V to 3.6 V				0.2	V
		I _{OL} = 4 mA	1.65 V				0.45	
		I _{OL} = 8 mA	2.3 V				0.7	
		I _{OL} = 12 mA	2.7 V				0.4	
		I _{OL} = 24 mA	3.0 V				0.55	
Input current	I _I	V _I = 5.5 V or GND	3.6 V				±5	μA
Three-state output leakage current	I _{OZ}	V _O = V _{CC} or GND	3.6 V				±10	μA
Quiescent supply current	I _{CC}	V _I = V _{CC} or GND I _O = 0 A	3.6 V				10	μA
Quiescent supply current delta	ΔI _{CC}	One input at V _{CC} - 0.6 V, Other inputs at V _{CC} or GND	2.7 V to 3.6 V				500	μA
Input capacitance	C _i	V _I = V _{CC} or GND	3.3 V	25°C		5 TYP		pF
Power dissipation capacitance per gate	C _{pd}	f = 10 MHz	1.8 V			7.4 TYP		pF
			2.5 V			11.3 TYP		
			3.3 V	15 TYP				

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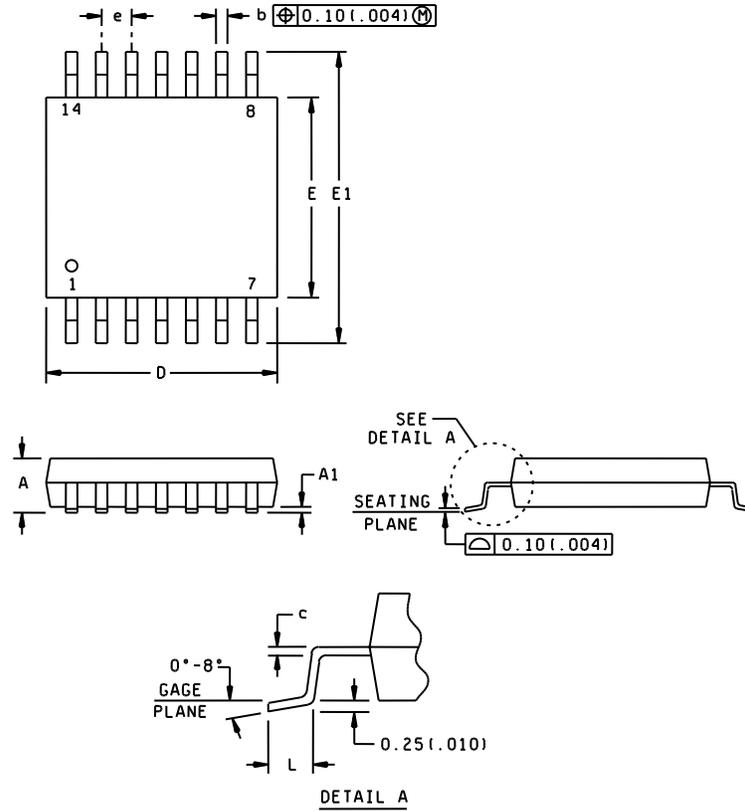
TABLE I. Electrical performance characteristics - Continued. 1/

Test	Symbol	Conditions	V _{CC}	Temperature, T _A	Device type	Limits		Unit
						Min	Max	
Propagation delay time, A to Y	t _{pd}	See figure 5.	1.8 V ±0.15 V	25°C, -40°C to 85°C	01	1	12.3	ns
			2.5 V ±0.2 V			1	6.3	
			2.7 V				5.5	
			3.3 V ±0.3 V			1	4.8	
			1.8 V ±0.15 V	25°C, -55°C to 125°C	02		12.3	ns
			2.5 V ±0.2 V				8	
			2.7 V				7	
			3.3 V ±0.3 V				5.8	
Propagation delay time, outputs enabled, OE to Y	t _{en}	See figure 5.	1.8 V ±0.15 V	25°C, -40°C to 85°C	01	1	14.3	ns
			2.5 V ±0.2 V			1	7.4	
			2.7 V				6.6	
			3.3 V ±0.3 V			1	5.4	
			1.8 V ±0.15 V	25°C, -55°C to 125°C	02		14.3	ns
			2.5 V ±0.2 V				9	
			2.7 V				8.5	
			3.3 V ±0.3 V				6.5	
Propagation delay time, outputs disabled, OE to Y	t _{dis}	See figure 5.	1.8 V ±0.15 V	25°C, -40°C to 85°C	01	1	11.1	ns
			2.5 V ±0.2 V			1	5.6	
			2.7 V				5	
			3.3 V ±0.3 V			1	4.6	
				25°C, -55°C to 125°C	02		11.1	ns
			1.8 V ±0.15 V				5.6	
			2.5 V ±0.2 V				6	
			2.7 V				5.6	
3.3 V ±0.3 V		5.6						
Output skew	t _{sk(o)}		3.3 V ±0.3 V	Device 01: 25°C, -40°C to 85°C, Device 02: 25°C, -55°C to 125°C	01, 02		1	ns

1/ Testing and other quality control techniques are used to the extent deemed necessary to assure product performance over the specified temperature range. Product may not necessarily be tested across the full temperature range and all parameters may not necessarily be tested. In the absence of specific parametric testing, product performance is assured by characterization and/or design.

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Case X



Dimensions									
Symbol	Millimeters		Inches		Symbol	Millimeters		Inches	
	Min	Max	Min	Max		Min	Max	Min	Max
A	---	1.20	---	0.047	E	4.30	4.50	0.169	0.177
A1	0.05	0.15	0.002	0.006	E1	6.20	6.60	0.244	0.260
b	0.19	0.30	0.007	0.012	e	0.65 BSC		0.026 BSC	
c	0.15 NOM		0.006 NOM		L	0.50	0.75	0.020	0.030
D	4.90	5.10	0.193	0.201					

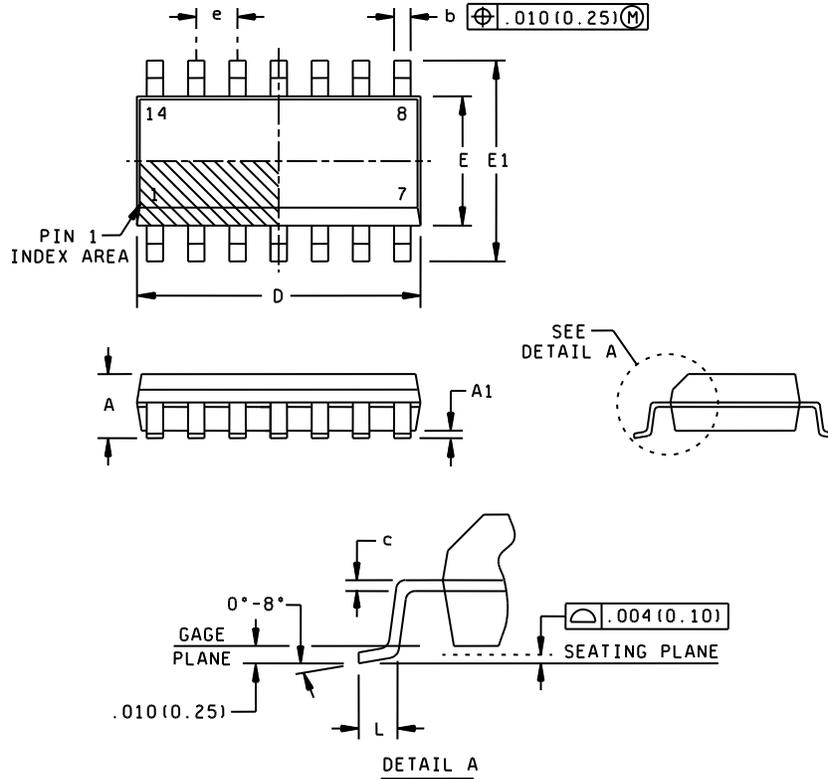
NOTES:

1. All linear dimensions are in millimeters (inches).
2. This case outline is subject to change without notice.
3. Body dimensions do not include mold flash or protrusion, not to exceed 0.15 millimeters (0.006 in).
4. Fall within JEDEC MO-153.

FIGURE 1. Case outlines.

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Case Y



Dimensions									
Symbol	Inches		Millimeters		Symbol	Inches		Millimeters	
	Min	Max	Min	Max		Min	Max	Min	Max
A	---	0.069	---	1.75	E	0.150	0.157	3.80	4.00
A1	0.004	0.010	0.10	0.25	E1	0.228	0.244	5.80	6.20
b	0.012	0.020	0.31	0.51	e	0.50 BSC		1.27 BSC	
c	0.007	0.010	0.17	0.25	L	0.016	0.050	0.40	1.27
D	0.337	0.344	8.55	8.75					

NOTES:

1. All linear dimensions are in inches (millimeters).
2. This case outline is subject to change without notice.
3. Body dimensions do not include mold flash or protrusion, not to exceed 0.006 in (0.15 millimeters).
4. Fall within JEDEC MS-012, variation AB.

FIGURE 1. Case outlines - Continued.

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(each buffer)

Inputs		Output
\overline{OE}	A	Y
L	H	H
L	L	L
H	X	Z

H = High voltage level
L = Low voltage level
X = Immaterial
Z = High impedance state

FIGURE 2. Truth table.

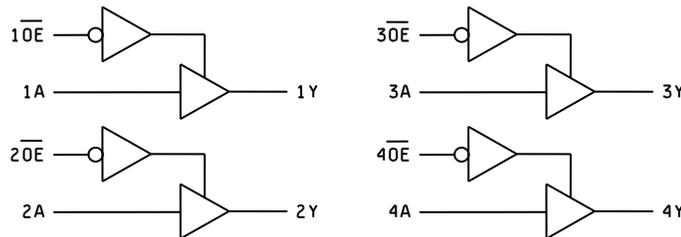
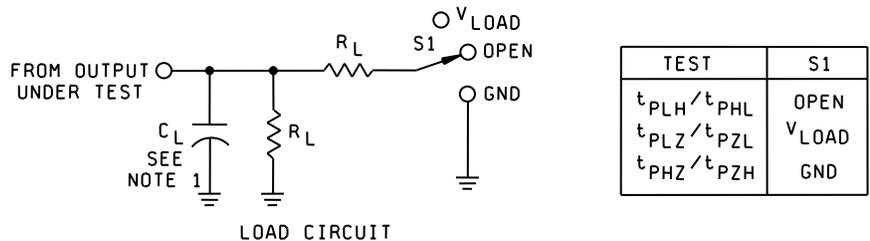


FIGURE 3. Logic diagram.

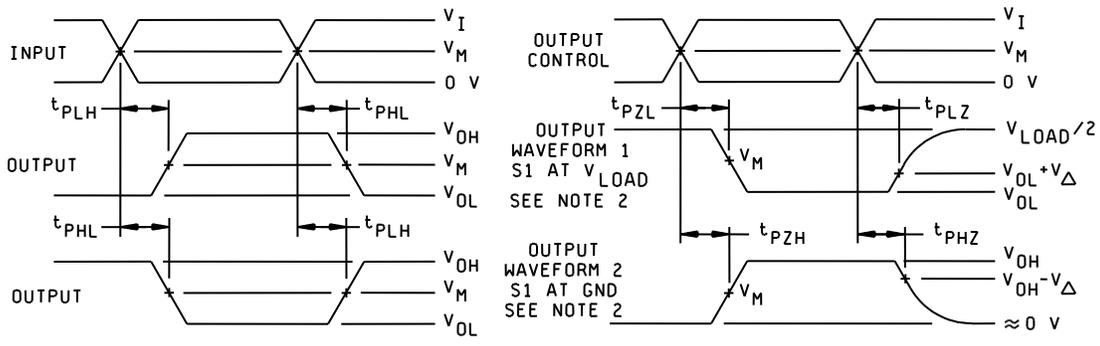
Case outlines:	X and Y		
Terminal number	Terminal symbol	Terminal number	Terminal symbol
1	$1\overline{OE}$	8	3Y
2	1A	9	3A
3	1Y	10	$3\overline{OE}$
4	$2\overline{OE}$	11	4Y
5	2A	12	4A
6	2Y	13	$4\overline{OE}$
7	GND	14	V _{CC}

FIGURE 4. Terminal connections.

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V_{CC}	INPUTS		V_M	V_{LOAD}	C_L	R_L	V_{Δ}
	V_I	t_r/t_f					
$1.8\text{ V} \pm 0.15\text{ V}$	V_{CC}	$\leq 2\text{ ns}$	$V_{CC}/2$	$2 \times V_{CC}$	30 pF	1 k Ω	0.15 V
$2.5\text{ V} \pm 0.2\text{ V}$	V_{CC}	$\leq 2\text{ ns}$	$V_{CC}/2$	$2 \times V_{CC}$	30 pF	500 Ω	0.15 V
2.7 V	2.7 V	$\leq 2.5\text{ ns}$	1.5 V	6 V	50 pF	500 Ω	0.3 V
$3.3\text{ V} \pm 0.3\text{ V}$	2.7 V	$\leq 2.5\text{ ns}$	1.5 V	6 V	50 pF	500 Ω	0.3 V



NOTES:

1. C_L includes probe and jig capacitance.
2. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
3. All input pulses are supplied by generators having the following characteristics: $PRR \leq 10\text{ MHz}$, $Z_O = 50\ \Omega$.
4. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
5. t_{PZL} and t_{PZH} are the same as t_{en} .
6. t_{PLH} and t_{PHL} are the same as t_{pd} .
7. The outputs are measured one at a time with one input transition per measurement.

FIGURE 5. Test circuit and timing waveforms.

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4. VERIFICATION

4.1 Product assurance requirements. The manufacturer is responsible for performing all inspection and test requirements as indicated in their internal documentation. Such procedures should include proper handling of electrostatic sensitive devices, classification, packaging, and labeling of moisture sensitive devices, as applicable.

5. PREPARATION FOR DELIVERY

5.1 Packaging. Preservation, packaging, labeling, and marking shall be in accordance with the manufacturer's standard commercial practices for electrostatic discharge sensitive devices.

6. NOTES

6.1 ESDS. Devices are electrostatic discharge sensitive and are classified as ESDS class 1 minimum.

6.2 Configuration control. The data contained herein is based on the salient characteristics of the device manufacturer's data book. The device manufacturer reserves the right to make changes without notice. This drawing will be modified as changes are provided.

6.3 Suggested source(s) of supply. Identification of the suggested source(s) of supply herein is not to be construed as a guarantee of present or continued availability as a source of supply for the item. DLA Land and Maritime maintains an online database of all current sources of supply at <http://www.landandmaritime.dla.mil/Programs/Smcr/>.

Vendor item drawing administrative control number ^{1/}	Device manufacturer CAGE code	Vendor part number	Top side marking
V62/04656-01XE	01295	SN74LVC125AIPWREP	C125AEP
V62/04656-02YE	01295	SN74LVC125AMDREP	125AMEP

^{1/} The vendor item drawing establishes an administrative control number for identifying the item on the engineering documentation.

CAGE code

01295

Source of supply

Texas Instruments, Inc.
 Semiconductor Group
 8505 Forest Lane
 P.O. Box 660199
 Dallas, TX 75243
 Point of contact: U.S. Highway 75 South
 P.O. Box 84, M/S 853
 Sherman, TX 75090-9493

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